## NSN 5961-01-094-7333

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-094-7333 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 25.0 drain to source voltage and 25.0 drain to gate voltage and -25.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 80063-sm-a-595830 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**